

FAST RECOVERY RECTIFIERS

REVERSE VOLTAGE: 50 --- 1000 V
CURRENT: 1A

GENERAL PURPOSE MOUNT SILICON

FEATURES

- * Fast switching
- * Glass passivated device
- * Ideal for surface mounted applications
- * Low leakage current
- * Metallurgically bonded construction
- * Mounting position: Any
- * Weight: 0.015 gram

MECHANICAL DATA

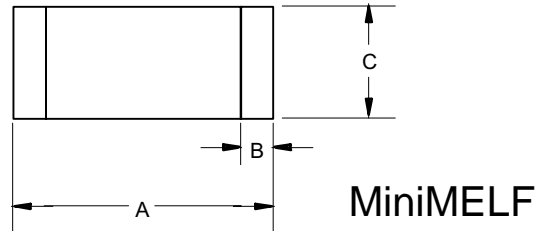
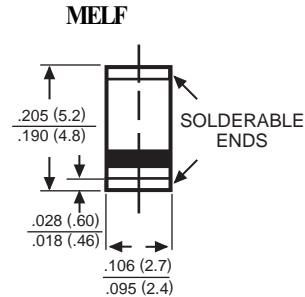
- * Epoxy : Device has UL flammability classification 94V-0

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.130	.146	3.30	3.70	
B	.008	.016	.20	.40	
C	.055	.059	1.40	1.50	∅

Dimensions in inches and (millimeters)

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	FSM101	FSM102	FSM103	FSM104	FSM105	FSM106	FSM107	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	Vdc	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at TA = 55°C	Io	1.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	30							Amps
Maximum Thermal Resistance	(Note 2) RθJL	30							°C/W
	(Note 3) RθJA	75							°C/W
Typical Junction Capacitance (Note 1)	CJ	15							pF
Operating and Storage Temperature Range	TJ, TSTG	-65 to + 175							°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	FSM101	FSM102	FSM103	FSM104	FSM105	FSM106	FSM107	UNITS
Maximum Forward Voltage at 1.0A DC	VF	1.3							Volts
Maximum Full Load Reverse Current, Full cycle Average at TA=55°C	IR	50							uAmps
Maximum Average Reverse Current at @TA = 25°C		5.0							uAmps
Rated DC Blocking Voltage @TA = 125°C		100							uAmps
Maximum Reverse Recovery Time (Note 4)	trr	150			250	500			nSec

- NOTES : 1. Measured at 1.0 MHz and applied average voltage of 4.0VDC
 2. Thermal resistance junction to terminal 6.0mm² copper pads to each terminal.
 3. Thermal resistance junction to ambient, 6.0mm² copper pads to each terminal.
 4. Test Conditions: IF = 0.5A, IR = -1.0A, IRR = -0.25A

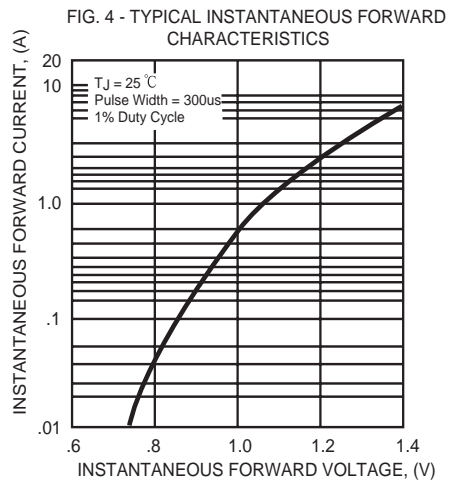
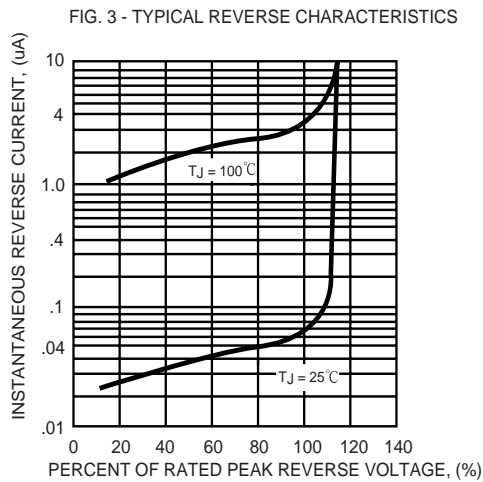
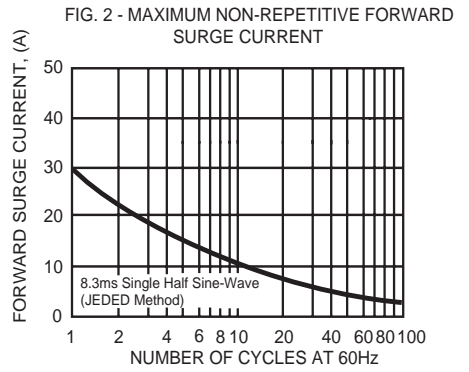
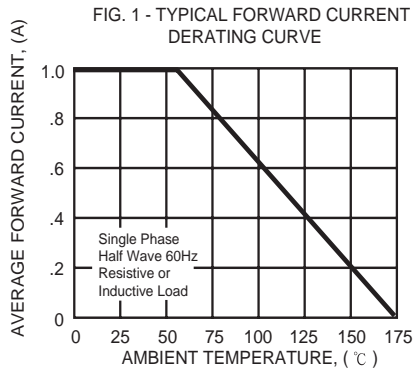
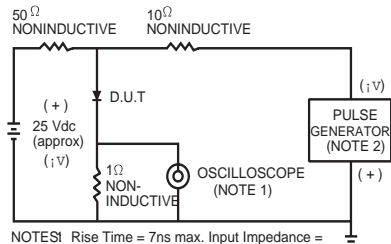


FIG. 5 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time = 7ns max. Input Impedance = 1 megohm. 22 pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.

